

# TMUX405x 24V, 8:1, 1-Channel, 4:1, 2-Channel and 2:1, 3-Channel Multiplexers with 1.8V Logic

## 1 Features

- Single supply range: 5V to 24V
- Dual supply range: up to  $\pm 12V$
- Low capacitance: 3pF
- $-55^{\circ}C$  to  $+125^{\circ}C$  operating temperature
- [Bidirectional signal path](#)
- [Rail-to-rail operation](#)
- [1.8V logic compatible](#)
- Break-before-make switching
- ESD protection HBM: 2000V
- TMUX405x – pin compatible with:
  - Industry standard 4051, 4052, and 4053 muxes

## 2 Applications

- Analog multiplexing and demultiplexing
- [Factory automation and control](#)
- [Appliances](#)
- [Battery test equipment](#)
- [Power delivery](#)
- [Medical](#)
- [Building automation](#)
- [Grid infrastructure](#)

## 3 Description

The TMUX405x devices are general purpose complementary metal-oxide semiconductor (CMOS) multiplexers (MUX). The TMUX4051 is an 8:1, 1-channel multiplexer, the TMUX4052 is a 4:1, 2-channel multiplexer, and the TMUX4053 is 2:1, 3 channel switch. The devices work with a single supply (5V to 24V), dual supplies (up to  $\pm 12V$ ), or asymmetric supplies (such as  $V_{DD} = 12V$ ,  $V_{SS} = -5V$ ). The wide supply voltage range allows the TMUX405x devices to be used in a broad array of applications from battery testers to appliances.

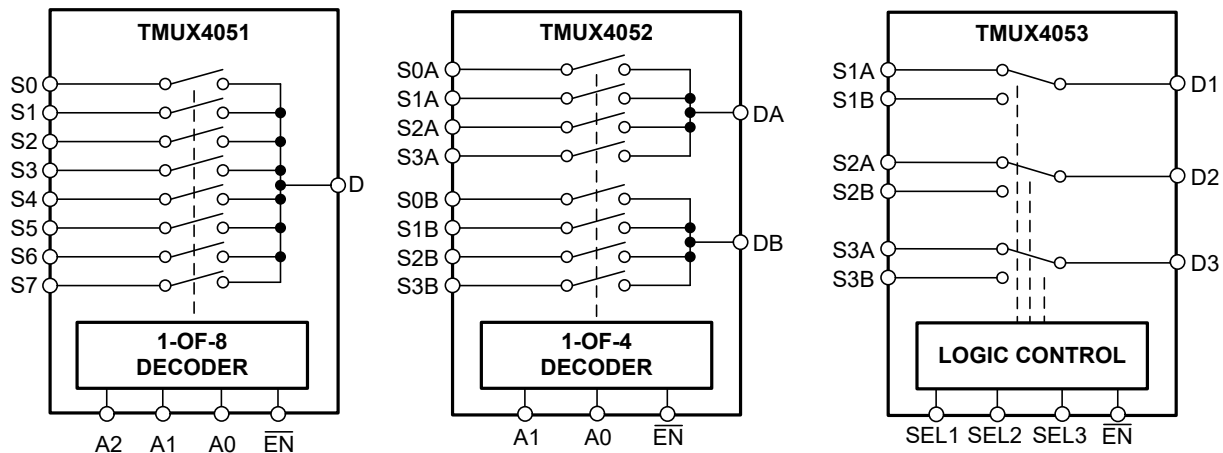
The TMUX405x devices support bidirectional analog signals on the source (Sx) and drain (Dx) pins ranging from  $V_{SS}$  to  $V_{DD}$ . All logic inputs have [1.8V logic compatible](#) thresholds, which is compatible for both TTL and CMOS logic when operating with a valid supply voltage.

**Table 3-1. Package Information**

PART NUMBER <sup>(1)</sup>	CHANNEL COUNT	PACKAGE <sup>(2)</sup>
TMUX4051	1-Channel	PW (TSSOP, 16)
TMUX4052	2-Channel	DYY (SOT-23-THIN, 16)
TMUX4053	3-Channel	BQB (WQFN, 16)

(1) See the [Device Comparison Table](#)

(2) For more information, see [Section 12](#).



**TMUX4051, TMUX4052, and TMUX4053 Block Diagram**



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## 4 Device Comparison Table

PRODUCT	DESCRIPTION
TMUX4051	8:1, 1-channel multiplexer
TMUX4052	4:1, 2-channel multiplexer
TMUX4053	2:1, 3-channel switch

## 5 Pin Configuration and Functions

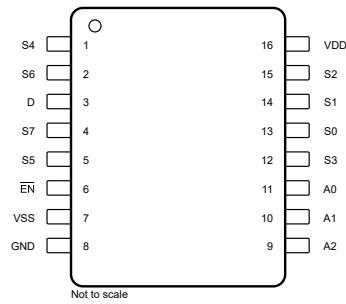


Figure 5-1. TMUX4051 PW Package, 16-Pin TSSOP (Top View)

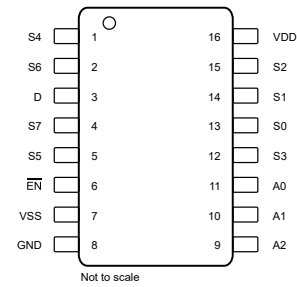


Figure 5-2. TMUX4051 DYY Package, 16-Pin SOT-23-THIN (Top View)

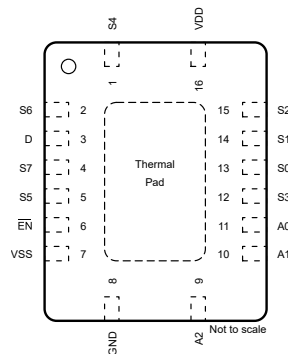


Figure 5-3. TMUX4051 BQB Package, 16-Pin WQFN (Top View)

Table 5-1. Pin Functions TMUX4051

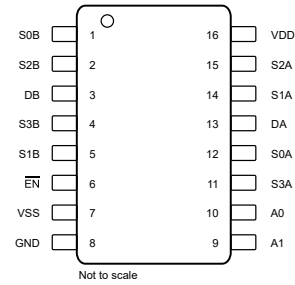
PIN		TYPE <sup>(1)</sup>	DESCRIPTION <sup>(2)</sup>
NAME	NO.		
S4	1	I/O	Source pin 4. Signal path can be an input or output.
S6	2	I/O	Source pin 6. Signal path can be an input or output.
D	3	I/O	Drain pin (common). Signal path can be an input or output.
S7	4	I/O	Source pin 7. Signal path can be an input or output.
S5	5	I/O	Source pin 5. Signal path can be an input or output.
$\overline{\text{EN}}$	6	I	Active low logic enable. When this pin is high, all switches are turned off. Table 8-1 lists how the A[2:0] address inputs determine which switch is turned on when this pin is low.
V <sub>SS</sub>	7	P	Negative power supply. This pin is the most negative power-supply potential. For reliable operation, connect a decoupling capacitor ranging from 0.1µF to 10µF between V <sub>SS</sub> and GND.
GND	8	P	Ground (0V) reference
A2	9	I	Address line 2. Table 8-1 provides information about how A2 controls the switch configuration.
A1	10	I	Address line 1. Table 8-1 provides information about how A1 controls the switch configuration.
A0	11	I	Address line 0. Table 8-1 provides information about how A0 controls the switch configuration.
S3	12	I/O	Source pin 3. Signal path can be an input or output.
S0	13	I/O	Source pin 0. Signal path can be an input or output.
S1	14	I/O	Source pin 1. Signal path can be an input or output.
S2	15	I/O	Source pin 2. Signal path can be an input or output.
V <sub>DD</sub>	16	P	Positive power supply. This pin is the most positive power-supply potential. For reliable operation, connect a decoupling capacitor ranging from 0.1µF to 10µF between V <sub>DD</sub> and GND.
Thermal pad		—	The thermal pad is not connected internally. It is recommended that the pad be left floating or tied to GND.

(1) I = input, O = output, I/O = input and output, P = power.

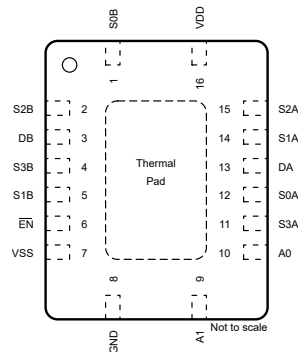
(2) For what to do with unused pins, refer to Section 8.3.4.



**Figure 5-4. TMUX4052 PW Package, 16-Pin TSSOP (Top View)**



**Figure 5-5. TMUX4052 DYY Package, 16-Pin SOT-23-THIN (Top View)**



**Figure 5-6. TMUX4052 BQB Package, 16-Pin WQFN (Top View)**

**Table 5-2. Pin Functions TMUX4052**

PIN		TYPE <sup>(1)</sup>	DESCRIPTION <sup>(2)</sup>
NAME	NO.		
S0B	1	I/O	Source pin 0 of mux B. Can be an input or output.
S2B	2	I/O	Source pin 2 of mux B. Can be an input or output.
DB	3	I/O	Drain pin (common) of mux B. Can be an input or output.
S3B	4	I/O	Source pin 3 of mux B. Can be an input or output.
S1B	5	I/O	Source pin 1 of mux B. Can be an input or output.
EN	6	I	Active low logic enable. When this pin is high, all switches are turned off. When this pin is low, the A[1:0] address inputs determine which switch is turned on.
V <sub>SS</sub>	7	P	Negative power supply. This pin is the most negative power-supply potential. For reliable operation, connect a decoupling capacitor ranging from 0.1µF to 10µF between V <sub>SS</sub> and GND.
GND	8	P	Ground (0V) reference
A1	9	I	Address line 1. <a href="#">Table 8-2</a> provides information about how A1 controls the switch configuration.
A0	10	I	Address line 0. <a href="#">Table 8-2</a> provides information about how A0 controls the switch configuration.
S3A	11	I/O	Source pin 3 of mux A. Can be an input or output.
S0A	12	I/O	Source pin 0 of mux A. Can be an input or output.
DA	13	I/O	Drain pin (common) of mux A. Can be an input or output.
S1A	14	I/O	Source pin 1 of mux A. Can be an input or output.
S2A	15	I/O	Source pin 2 of mux A. Can be an input or output.
V <sub>DD</sub>	16	P	Positive power supply. This pin is the most positive power-supply potential. For reliable operation, connect a decoupling capacitor ranging from 0.1µF to 10µF between V <sub>DD</sub> and GND.
Thermal pad		—	The thermal pad is not connected internally. It is recommended that the pad be left floating or tied to GND.

- (1) I = input, O = output, I/O = input and output, P = power.  
(2) For what to do with unused pins, refer to [Section 8.3.4](#).

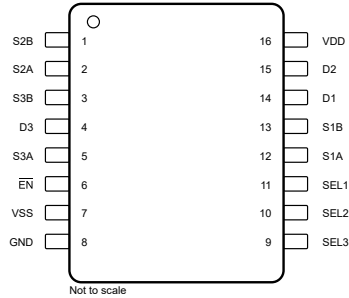


Figure 5-7. TMUX4053 PW Package, 16-Pin TSSOP (Top View)

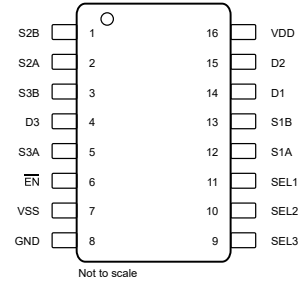


Figure 5-8. TMUX4053 DYY Package, 16-Pin SOT-23-THIN (Top View)

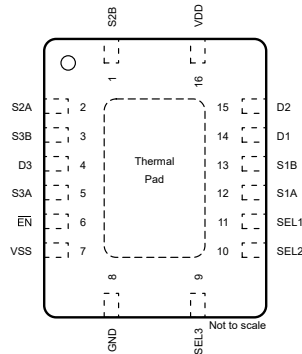


Figure 5-9. TMUX4053 BQB Package, 16-Pin WQFN (Top View)

Table 5-3. Pin Functions TMUX4053

PIN		TYPE <sup>(1)</sup>	DESCRIPTION <sup>(2)</sup>
NAME	NO.		
S2B	1	I/O	Source pin B of switch 2. Can be an input or output.
S2A	2	I/O	Source pin A of switch 2. Can be an input or output.
S3B	3	I/O	Source pin B of switch 3. Can be an input or output.
D3	4	I/O	Drain pin (common) of switch 3. Can be an input or output.
S3A	5	I/O	Source pin A of switch 3. Can be an input or output.
EN	6	I	Active low logic enable. When this pin is high, all switches are turned off. When this pin is low, the SEL[x] logic control inputs determine which switch is turned on.
V <sub>SS</sub>	7	P	Negative power supply. This pin is the most negative power-supply potential. For reliable operation, connect a decoupling capacitor ranging from 0.1µF to 10µF between V <sub>SS</sub> and GND.
GND	8	P	Ground (0V) reference
SEL3	9	I	Logic control select pin 3. <a href="#">Table 8-2</a> provides controls switch 3 configuration.
SEL2	10	I	Logic control select pin 2. <a href="#">Table 8-2</a> provides controls switch 2 configuration.
SEL1	11	I	Logic control select pin 1. <a href="#">Table 8-2</a> provides controls switch 1 configuration.
S1A	12	I/O	Source pin A of switch 1. Can be an input or output.
S1B	13	I/O	Source pin B of switch 1. Can be an input or output.
D1	14	I/O	Drain pin (common) of switch 1. Can be an input or output.
D2	15	I/O	Drain pin (common) of switch 2. Can be an input or output.
V <sub>DD</sub>	16	P	Positive power supply. This pin is the most positive power-supply potential. For reliable operation, connect a decoupling capacitor ranging from 0.1µF to 10µF between V <sub>DD</sub> and GND.
Thermal pad		—	The thermal pad is not connected internally. It is recommended that the pad be left floating or tied to GND.

(1) I = input, O = output, I/O = input and output, P = power.

(2) For what to do with unused pins, refer to [Section 8.3.4](#).

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1) (3)</sup>

		MIN	MAX	UNIT
$V_{DD} - V_{SS}$	Supply voltage		28	V
$V_{DD}$		-0.5	28	V
$V_{SS}$		-28	0.5	V
$V_{SEL}$ or $V_{EN}$	Logic control input pin voltage ( $\overline{EN}$ , Ax, SELx)	-0.5	28	V
$I_{SEL}$ or $I_{EN}$	Logic control input pin current ( $\overline{EN}$ , Ax, SELx)	-0.5	28	mA
$V_S$ or $V_D$	Source or drain voltage (Sx, D)	$V_{SS}-0.5$	$V_{DD}+0.5$	V
$I_{IK}$	Diode clamp current <sup>(2)</sup>	-30	30	mA
$I_S$ or $I_D$ (CONT)	Source or drain continuous current (Sx, D)	-10	10	mA
$T_J$	Junction temperature		150	°C
$T_{stg}$	Storage temperature	-65	150	°C

- (1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. Absolute maximum ratings do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If briefly operating outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not sustain damage, but it may not be fully functional. Operating the device in this manner may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) Pins are diode-clamped to the power-supply rails. Over voltage signals must be voltage and current limited to maximum ratings.
- (3) To avoid drawing excess current from  $V_{DD}$ , or into  $V_{SS}$ , the voltage drop across the bidirectional switch path ( $\Delta V_{switch}$ ) must not exceed 1.2V (600mV for high temperature).

### 6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>	±2000	V
		Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002, all pins <sup>(2)</sup>	±500	

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Thermal Information: TMUX405x

THERMAL METRIC <sup>(1)</sup>		TMUX4051 / TMUX4052 / TMUX4053			UNIT
		PW (TSSOP)	DYY (SOT)	BQB (WQFN)	
		16 PINS	16 PINS	16 PINS	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	116.5	138.9	70.5	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	47.2	70.3	67.8	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	63.0	69.1	40.2	°C/W
Ψ <sub>JT</sub>	Junction-to-top characterization parameter	6.4	5.1	3.9	°C/W
Ψ <sub>JB</sub>	Junction-to-board characterization parameter	62.1	69.0	40.2	°C/W
R <sub>θJC(bot)</sub>	Junction-to-case (bottom) thermal resistance	N/A	N/A	18.7	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

### 6.4 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V <sub>DD</sub> – V <sub>SS</sub> <sup>(1)</sup>	Power supply voltage differential	5		24	V
V <sub>DD</sub>	Positive power supply voltage	5		24	V
V <sub>SS</sub>	Negative power supply voltage	–15		0	V
V <sub>S</sub> or V <sub>D</sub>	Signal path input/output voltage (source or drain pin) (Sx, D)	V <sub>SS</sub>		V <sub>DD</sub>	V
V <sub>AX</sub> or V <sub>EN</sub>	Address or enable pin voltage	0		V <sub>DD</sub>	V
I <sub>S</sub> or I <sub>D (CONT)</sub>	Source or drain continuous current (Sx, D)	–10		10	mA
T <sub>A</sub>	Ambient temperature	–55		125	°C

(1) V<sub>DD</sub> and V<sub>SS</sub> can be any value as long as 5V ≤ (V<sub>DD</sub> – V<sub>SS</sub>) ≤ 24V, and the minimum V<sub>DD</sub> and V<sub>SS</sub> are met.



## 6.5 Electrical Characteristics

Over operating free-air temperature range,  
Typical at  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$V_{DD}$	$V_{SS}$	$T_A$	MIN	TYP	MAX	UNIT
<b>POWER SUPPLY</b>								
Supply current $I_{DD}$	Address inputs = 0V, 5V, or $V_{DD}$ $\overline{EN} = 0V$	5V	0V	-55°C			60	$\mu\text{A}$
				25°C		17	60	
				85°C			80	
				125°C			80	
	Address inputs = 0V, 5V, or $V_{DD}$ $\overline{EN} = 0V$	10V	0V	-55°C			60	
				25°C		18	60	
				85°C			80	
				125°C			80	
	Address inputs = 0V, 5V, or $V_{DD}$ $\overline{EN} = 0V$	24V	0V	-55°C			60	
				25°C		21	60	
				85°C			80	
				125°C			80	
	Address inputs = 0V, 5V, or $V_{DD}$ $\overline{EN} = 0V$	5V	-5V	-55°C			60	
				25°C		18	60	
				85°C			80	
				125°C			80	
Address inputs = 0V, 5V, or $V_{DD}$ $\overline{EN} = 0V$	12V	-12V	-55°C			60		
			25°C		20	60		
			85°C			80		
			125°C			80		
Negative supply current $I_{SS}$	Address inputs = 0V, 5V, or $V_{DD}$ $\overline{EN} = 0V$	5V	-5V	-55°C			20	$\mu\text{A}$
				25°C		6	20	
				85°C			25	
				125°C			25	
	Address inputs = 0V, 5V, or $V_{DD}$ $\overline{EN} = 0V$	12V	-12V	-55°C			22	
				25°C		7	22	
				85°C			26	
				125°C			26	
$I_{DD}$ disable	$\overline{EN} = 5V$ or $V_{DD}$	All		25°C		8	$\mu\text{A}$	
				-55°C to 125°C				20

## 6.5 Electrical Characteristics (continued)

Over operating free-air temperature range,  
 Typical at  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$V_{DD}$	$V_{SS}$	$T_A$	MIN	TYP	MAX	UNIT
<b>ANALOG SWITCH</b>								
$R_{ON}$ Source to Drain ON-Resistance	$V_S = V_{SS}$ to $V_{DD}$ $I_D = -1\text{mA}$	5V	0V	$-55^\circ\text{C}$			800	$\Omega$
				$25^\circ\text{C}$	75	1050		
				$85^\circ\text{C}$		1200		
				$125^\circ\text{C}$		1300		
	$V_S = V_{SS}$ to $V_{DD}$ $I_D = -1\text{mA}$	10V	0V	$-55^\circ\text{C}$			310	
				$25^\circ\text{C}$	60	400		
				$85^\circ\text{C}$		520		
				$125^\circ\text{C}$		550		
	$V_S = V_{SS}$ to $V_{DD}$ $I_D = -1\text{mA}$	24V	0V	$-55^\circ\text{C}$			200	
				$25^\circ\text{C}$	60	240		
				$85^\circ\text{C}$		300		
				$125^\circ\text{C}$		300		
	$V_S = V_{SS}$ to $V_{DD}$ $I_D = -1\text{mA}$	5V	-5V	$-55^\circ\text{C}$			310	
				$25^\circ\text{C}$	60	400		
				$85^\circ\text{C}$		520		
				$125^\circ\text{C}$		550		
	$V_S = V_{SS}$ to $V_{DD}$ $I_D = -1\text{mA}$	12V	-12V	$-55^\circ\text{C}$			200	
				$25^\circ\text{C}$	60	240		
				$85^\circ\text{C}$		300		
				$125^\circ\text{C}$		300		
$\Delta R_{ON}$	$V_S = V_{SS}$ to $V_{DD}$ $I_D = -1\text{mA}$	All		$25^\circ\text{C}$		2		$\Omega$
$R_{ON\ FLAT}$	$V_S = V_{SS}$ to $V_{DD}$ $I_D = -1\text{mA}$	All		$25^\circ\text{C}$		60		$\Omega$
				$-55^\circ\text{C}$ to $85^\circ\text{C}$		150		
				$-55^\circ\text{C}$ to $125^\circ\text{C}$		150		
$I_{S(OFF)}$ $I_{D(OFF)}$	Switch State is off $V_S = V_{SS} / V_{DD}$ $V_D = V_{DD} / V_{SS}$	24V	0V	$25^\circ\text{C}$	$\pm 0.3$	$\pm 100$		nA
				$-55^\circ\text{C}$ to $85^\circ\text{C}$		$\pm 200$		
				$-55^\circ\text{C}$ to $125^\circ\text{C}$		$\pm 1000$		
$I_{ON}$	Switch State is on $V_S = V_D = V_{SS}$ or $V_{DD}$	24V	0V	$25^\circ\text{C}$	$\pm 0.3$	$\pm 100$		nA
				$-55^\circ\text{C}$ to $85^\circ\text{C}$		$\pm 200$		
				$-55^\circ\text{C}$ to $125^\circ\text{C}$		$\pm 1000$		
<b>LOGIC INPUTS (ADDRESS / ENABLE pins)</b>								
$V_{IH}$	Input High Voltage	All		$-55^\circ\text{C}$ to $125^\circ\text{C}$	1.35		$V_{DD}$	V
$V_{IL}$	Input Low Voltage	All		$-55^\circ\text{C}$ to $125^\circ\text{C}$	0		0.8	V
$I_{IH}$ $I_{IL}$ Logic Input Current	$V_{LOGIC} = 0\text{V}, 5\text{V}, \text{ or } V_{DD}$	All		$25^\circ\text{C}$	$\pm 0.6$			$\mu\text{A}$
				$-55^\circ\text{C}$ to $125^\circ\text{C}$	-1	1		
$C_{IN}$		All		$25^\circ\text{C}$		2		pF

## 6.6 AC Performance Characteristics

Typical at  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS				$T_A = -55^\circ\text{C to } 125^\circ\text{C}$			UNIT
	CONDITION	$V_{DD}$	$V_{SS}$	GPN	MIN	TYP	MAX	
<b>CAPACITANCE</b>								
$C_{S(OFF)}$	$V_S = (V_{DD} + V_{SS}) / 2V$ $f = 1\text{MHz}$	5V	-5V	All	3			pF
		24V	0V		3			
$C_{D(OFF)}$	$V_S = (V_{DD} + V_{SS}) / 2V$ $f = 1\text{MHz}$	5V	-5V	TMUX4051	11			pF
		24V	0V		9			
		5V	-5V	TMUX4052	6			
		24V	0V		5			
		5V	-5V	TMUX4053	4			
		24V	0V		3			
$C_{S(ON)}$ $C_{D(ON)}$	$V_S = (V_{DD} + V_{SS}) / 2V$ $f = 1\text{MHz}$	5V	-5V	TMUX4051	13			pF
		24V	0V		11			
		5V	-5V	TMUX4052	8			
		24V	0V		7			
		5V	-5V	TMUX4053	10			
		24V	0V		5			
<b>DYNAMIC CHARACTERISTICS</b>								
Bandwidth (BW) (Sine Wave Input)	$V_{BIAS} = (V_{DD} + V_{SS}) / 2$ <sup>(1)</sup> $V_S = 200\text{mVpp}$ $R_L = 50\Omega, C_L = 5\text{pF}$	+5V	-5V	TMUX4051	280			MHz
		24V	0V		430			
		+5V	-5V	TMUX4052	600			
		24V	0V		700			
		+5V	-5V	TMUX4053	750			
		24V	0V		850			
Off Isolation Channel OFF (Sine Wave Input)	$V_{BIAS} = (V_{DD} + V_{SS}) / 2$ <sup>(1)</sup> $V_S = 200\text{mVpp}$ $R_L = 50\Omega, C_L = 5\text{pF}$ $f = 1\text{MHz}$	+5V	-5V	All	-95			dB
		24V	0V		-95			
Crosstalk (Sine Wave Input)	$V_{BIAS} = (V_{DD} + V_{SS}) / 2$ <sup>(1)</sup> $V_S = 200\text{mVpp}$ $R_L = 50\Omega, C_L = 5\text{pF}$ $f = 1\text{MHz}$	+5V	-5V	All	-90			dB
		24V	0V		-90			
Charge Injection	$V_S = (V_{DD} + V_{SS}) / 2$ $R_S = 0\Omega, C_L = 100\text{pF}$	+5V	-5V	TMUX4051	6			pC
		24V	0V		2			

(1) Peak-to-Peak voltage symmetrical about  $(V_{DD} + V_{SS}) / 2$ .

## 6.7 Timing Characteristics

Over operating free-air temperature range,  
 Typical at  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS				MIN	TYP	MAX	UNIT
		CONDITION	V <sub>DD</sub>	V <sub>SS</sub>	T <sub>A</sub>				
Prop Delay	Signal Input to Signal Output	$V_S = V_{SS}$ to $V_{DD}$	5V	0V	25°C		4	20	ns
			10V	0V	25°C		4	20	
			24V	0V	25°C		3	20	
			5V	-5V	25°C		4	20	
			12V	-12V	25°C		3	20	
t <sub>TRAN</sub>	Address-to-Signal OUT Transition time between inputs	t <sub>r</sub> , t <sub>f</sub> = 20ns, C <sub>L</sub> = 50pF, R <sub>L</sub> = 10kΩ	5V	0V	25°C		105		ns
					-55°C to +125°C		190		
			10V	0V	25°C		100		ns
					-55°C to +125°C		190		
			24V	0V	25°C		110		ns
					-55°C to +125°C		230		
			5V	-5V	25°C		100		ns
					-55°C to +125°C		190		
			12V	-12V	25°C		100		ns
					-55°C to +125°C		190		
t <sub>ON (EN)</sub>	Enable-to-Signal OUT Channel turning ON	t <sub>r</sub> , t <sub>f</sub> = 20ns, C <sub>L</sub> = 50pF, R <sub>L</sub> = 10kΩ	5V	0V	25°C		100		ns
					-55°C to +125°C		190		
			10V	0V	25°C		95		ns
					-55°C to +125°C		190		
			24V	0V	25°C		110		ns
					-55°C to +125°C		230		
			5V	-5V	25°C		100		ns
					-55°C to +125°C		190		
			12V	-12V	25°C		100		ns
					-55°C to +125°C		190		
t <sub>OFF (EN)</sub>	Enable-to-Signal OUT Channel turning OFF	t <sub>r</sub> , t <sub>f</sub> = 20ns, C <sub>L</sub> = 50pF, R <sub>L</sub> = 10kΩ	5V	0V	25°C		90		ns
					-55°C to +125°C		140		
			10V	0V	25°C		90		ns
					-55°C to +125°C		140		
			24V	0V	25°C		85		ns
					-55°C to +125°C		140		
			5V	-5V	25°C		100		ns
					-55°C to +125°C		160		
			12V	-12V	25°C		90		ns
					-55°C to +125°C		140		

## 6.7 Timing Characteristics (continued)

Over operating free-air temperature range,  
Typical at  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
		CONDITION	V <sub>DD</sub>	V <sub>SS</sub>				
t <sub>BBM</sub>		C <sub>L</sub> = 15pF, R <sub>L</sub> = 10kΩ	5V	0V	25°C		60	ns
					–55°C to +125°C	1		
			10V	0V	25°C		45	
					–55°C to +125°C	1		
			5V	–5V	25°C		45	
					–55°C to +125°C	1		
			12V	–12V	25°C		55	
					–55°C to +125°C	1		
			24V	0V	25°C		75	
					–55°C to +125°C	1		

## 6.8 Typical Characteristics

at  $T_A = 25^\circ\text{C}$ ,  $V_{DD} = 5\text{V}$  (unless otherwise noted)

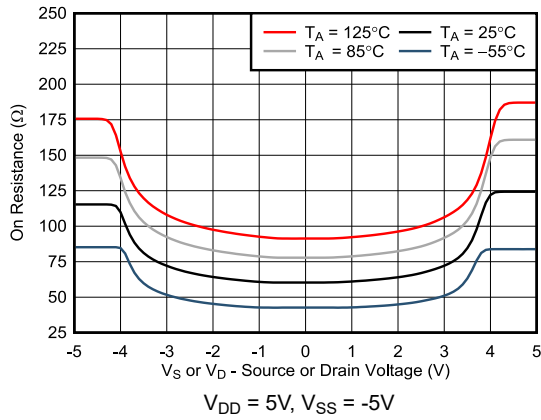


Figure 6-1. On-Resistance vs Temperature

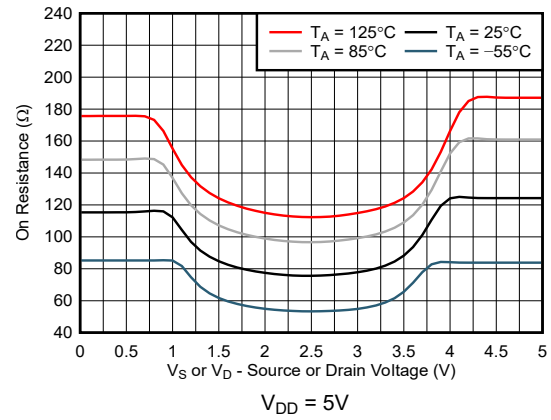


Figure 6-2. On-Resistance vs Temperature

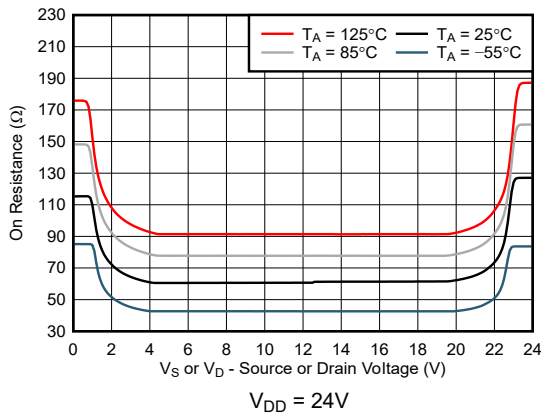


Figure 6-3. On-Resistance vs Temperature

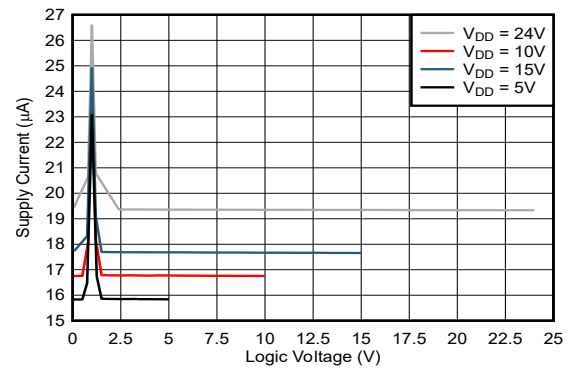


Figure 6-4. Supply Current vs Logic Voltage

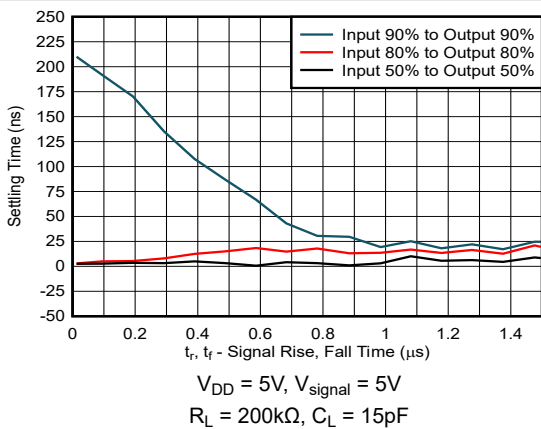


Figure 6-5. System Settling Time

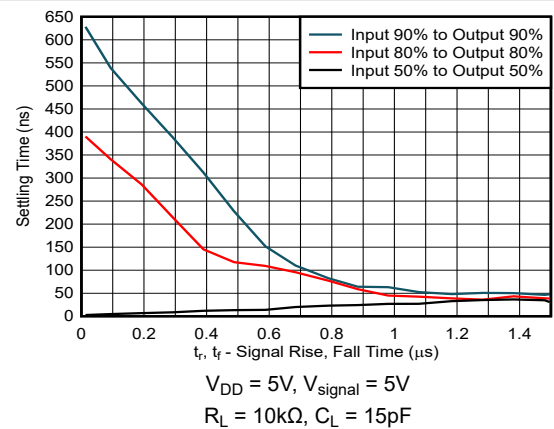
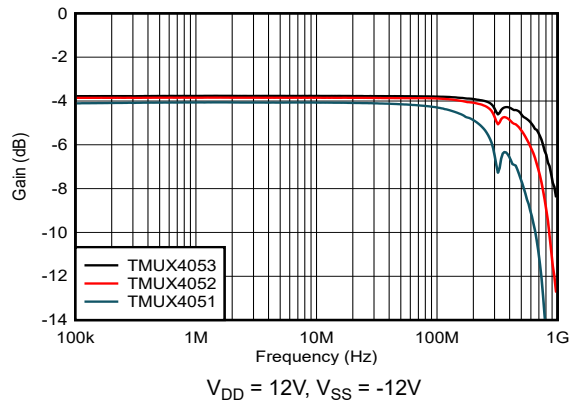


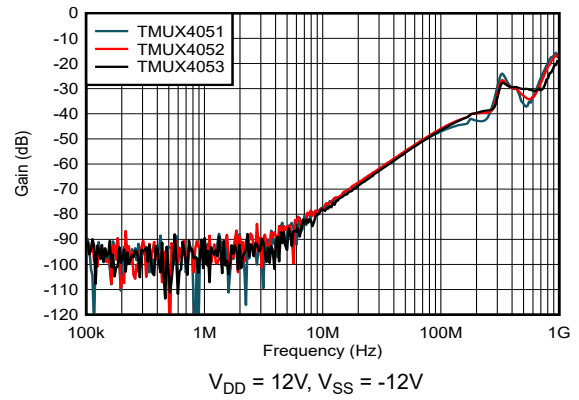
Figure 6-6. System Settling Time

## 6.8 Typical Characteristics (continued)

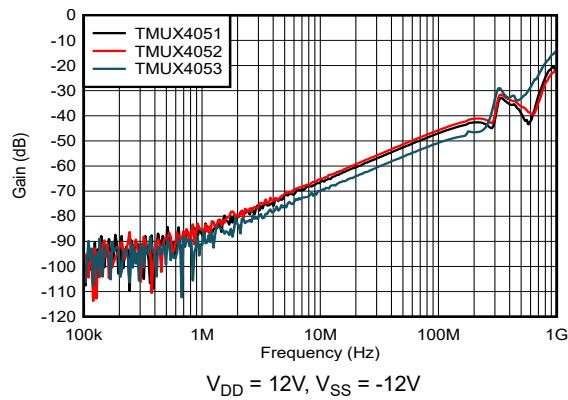
at  $T_A = 25^\circ\text{C}$ ,  $V_{DD} = 5\text{V}$  (unless otherwise noted)



**Figure 6-7. On Response vs Frequency**



**Figure 6-8. Off-Isolation vs Frequency**



**Figure 6-9. Xtalk vs Frequency**

## 7 Parameter Measurement Information

### 7.1 On-Resistance

The on-resistance of a device is the ohmic resistance between the source (Sx) and drain (D) pins of the device. The on-resistance varies with input voltage and supply voltage. The symbol  $R_{ON}$  is used to denote on-resistance. The measurement setup used to measure  $R_{ON}$  is shown in the following figure. Figure 7-1 shows how the  $R_{ON}$  is computed with  $R_{ON} = V / I_{SD}$ , and the voltage (V) and current ( $I_{SD}$ ) are measured using this setup.

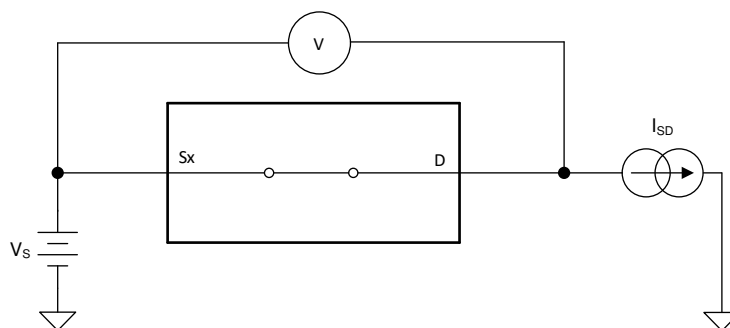


Figure 7-1. On-Resistance Measurement Setup

### 7.2 Off-Leakage Current

There are two types of leakage currents associated with a switch during the off state:

1. Source off-leakage current.
2. Drain off-leakage current.

Source leakage current is defined as the leakage current flowing into or out of the source pin when the switch is off. This current is denoted by the symbol  $I_{S(OFF)}$ .

Drain leakage current is defined as the leakage current flowing into or out of the drain pin when the switch is off. This current is denoted by the symbol  $I_{D(OFF)}$ .

Figure 7-2 shows the setup used to measure both off-leakage currents.

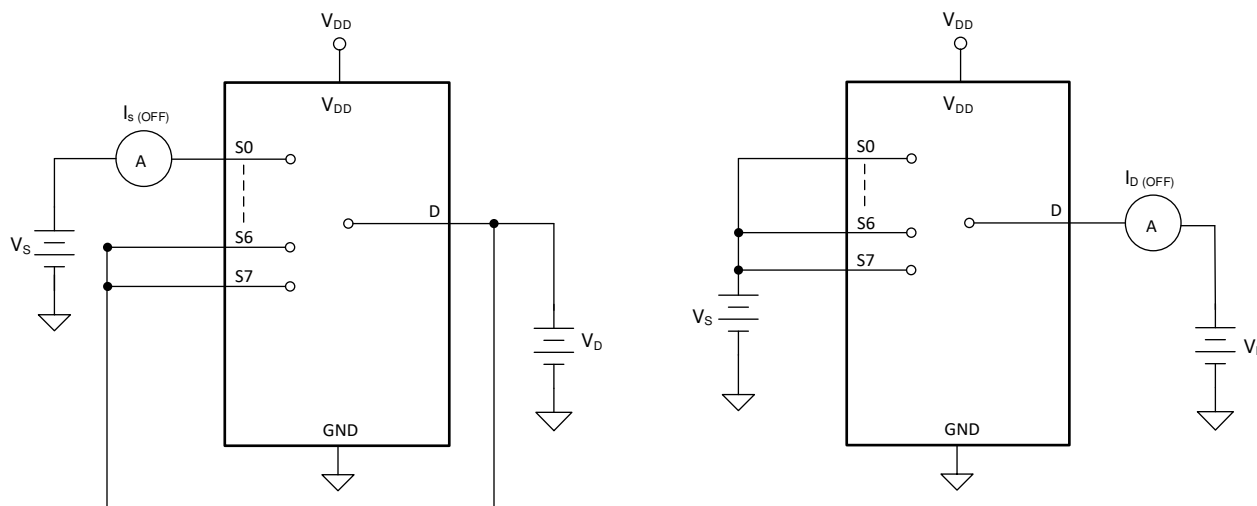


Figure 7-2. Off-Leakage Measurement Setup

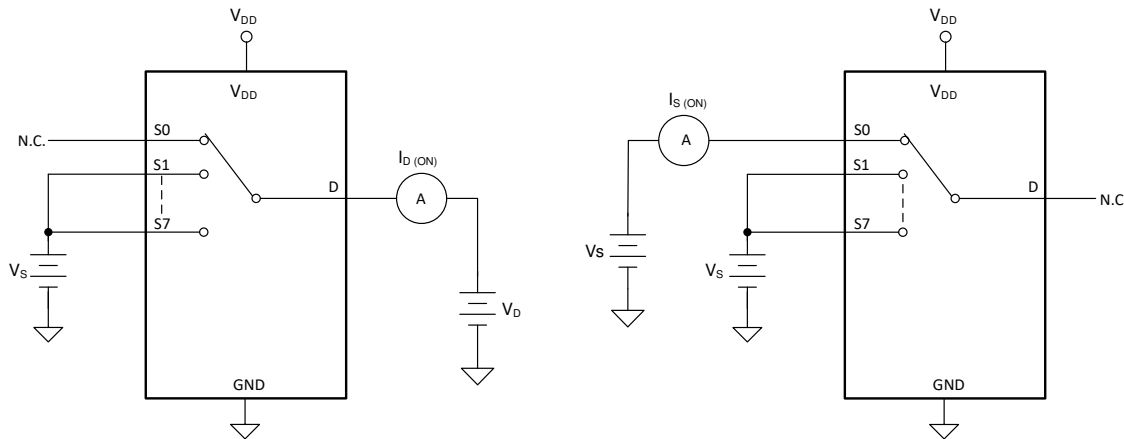


### 7.3 On-Leakage Current

Source on-leakage current is defined as the leakage current flowing into or out of the source pin when the switch is on. This current is denoted by the symbol  $I_{S(ON)}$ .

Drain on-leakage current is defined as the leakage current flowing into or out of the drain pin when the switch is on. This current is denoted by the symbol  $I_{D(ON)}$ .

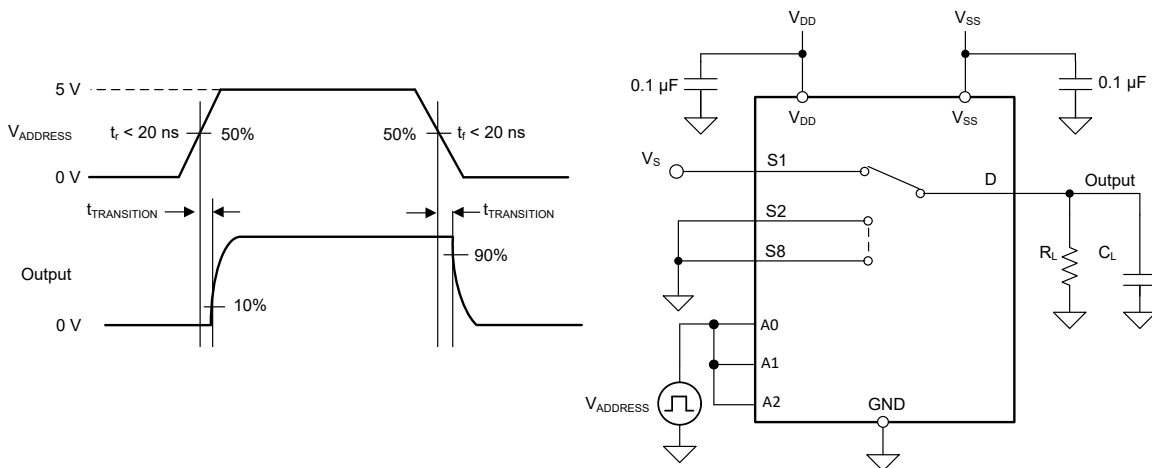
Either the source pin or drain pin is left floating during the measurement. Figure 7-3 shows the circuit used for measuring the on-leakage current, denoted by  $I_{S(ON)}$  or  $I_{D(ON)}$ .



**Figure 7-3. On-Leakage Measurement Setup**

### 7.4 Transition Time

Transition time is defined as the time taken by the output of the device to rise or fall 10% after the address signal has risen or fallen past the 50% threshold. Figure 7-4 shows the setup used to measure transition time, denoted by the symbol  $t_{TRANSITION}$ .



**Figure 7-4. Transition-Time Measurement Setup**

## 7.5 Break-Before-Make

Break-before-make delay is a safety feature that prevents two inputs from connecting when the device is switching. The output first breaks from the on-state switch before making the connection with the next on-state switch. The time delay between the *break* and the *make* is known as break-before-make delay. Figure 7-5 shows the setup used to measure break-before-make delay, denoted by the symbol  $t_{OPEN(BBM)}$ .

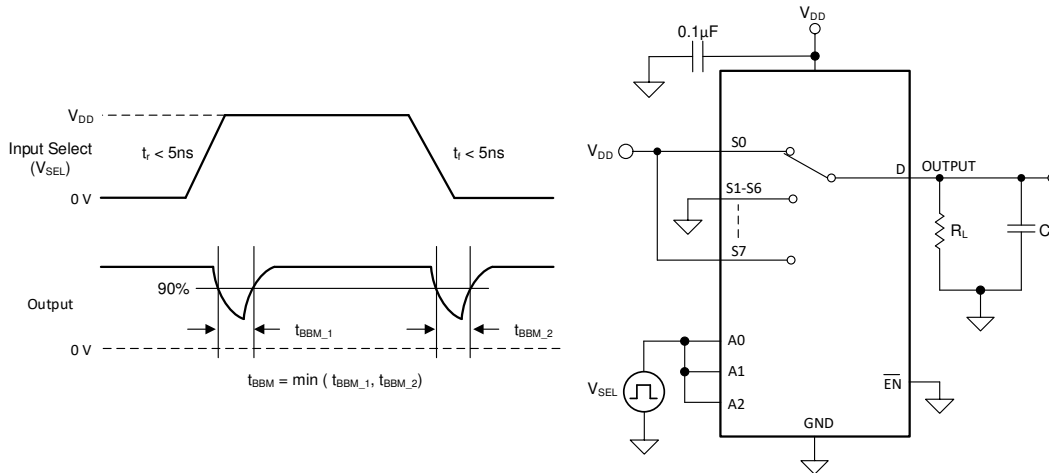


Figure 7-5. Break-Before-Make Delay Measurement Setup

## 7.6 $t_{ON(EN)}$ and $t_{OFF(EN)}$

Turn-on time is defined as the time taken by the output of the device to rise to 10% after the enable has risen past the 50% threshold. The 10% measurement is utilized to provide the timing of the device, system level timing can then account for the time constant added from the load resistance and load capacitance. Figure 7-6 shows the setup used to measure transition time, denoted by the symbol  $t_{ON(EN)}$ .

Turn-off time is defined as the time taken by the output of the device to fall to 90% after the enable has fallen past the 50% threshold. The 90% measurement is utilized to provide the timing of the device, system level timing can then account for the time constant added from the load resistance and load capacitance. Figure 7-6 shows the setup used to measure transition time, denoted by the symbol  $t_{OFF(EN)}$ .

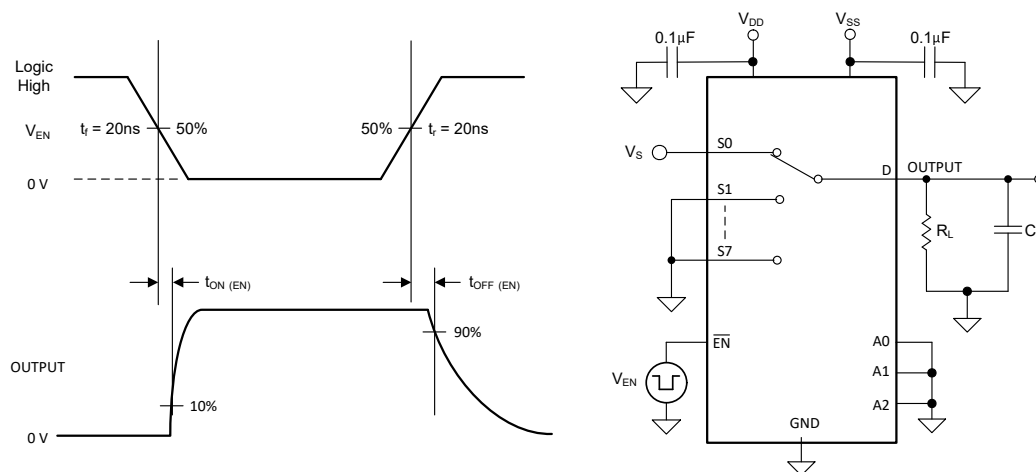
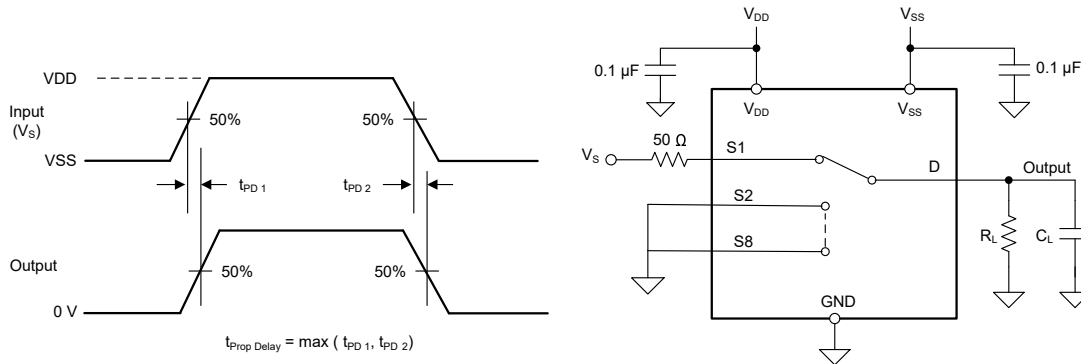


Figure 7-6. Turn-On and Turn-Off Time Measurement Setup

### 7.7 Propagation Delay

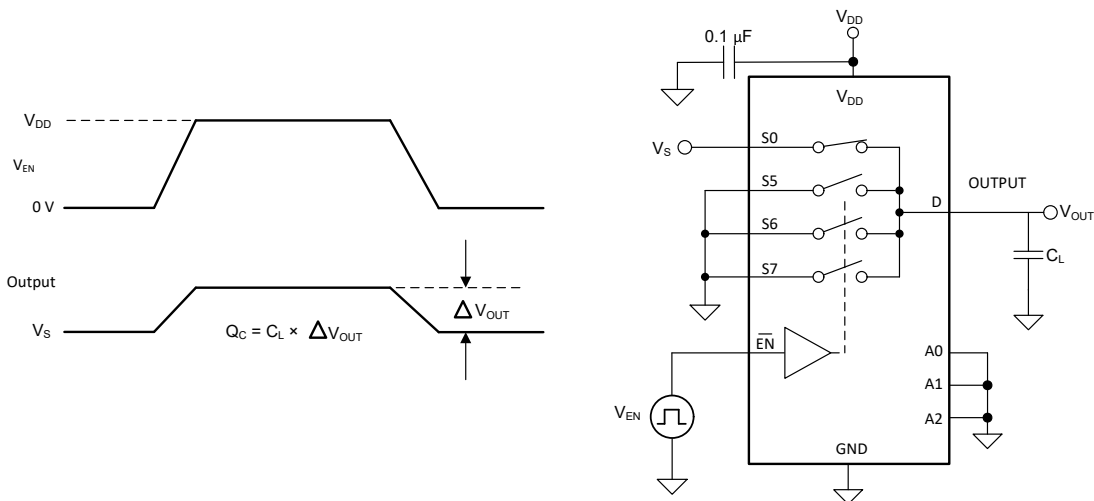
Propagation delay is defined as the time taken by the output of the device to rise or fall 50% after the input signal has risen or fallen past the 50% threshold. Figure 7-7 shows the setup used to measure propagation delay, denoted by the symbol  $t_{PD}$ .



**Figure 7-7. Propagation Delay Measurement Setup**

### 7.8 Charge Injection

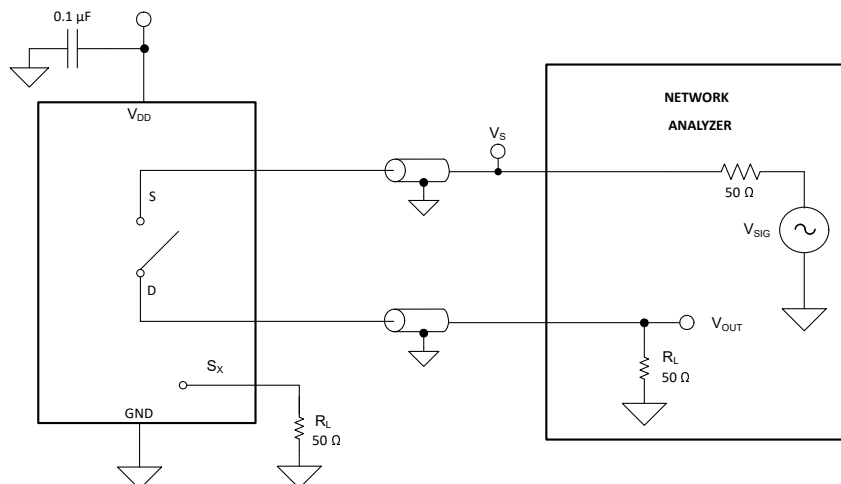
Any mismatch in capacitance between the NMOS and PMOS transistors results in a charge injected into the drain or source during the falling or rising edge of the gate signal. The amount of charge injected into the source or drain of the device is known as charge injection, and is denoted by the symbol  $Q_C$ . Figure 7-8 shows the setup used to measure charge injection from source (Sx) to drain (D).



**Figure 7-8. Charge-Injection Measurement Setup**

## 7.9 Off Isolation

Off isolation is defined as the ratio of the signal at the drain pin (D) of the device when a signal is applied to the source pin (S<sub>x</sub>) of an off-channel. Figure 7-9 shows the setup used to measure, and the equation to compute off isolation.

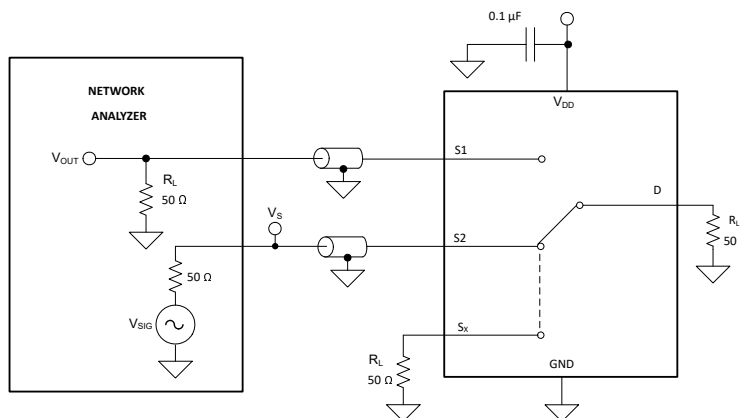


**Figure 7-9. Off Isolation Measurement Setup**

$$\text{Off Isolation} = 20 \times \text{Log} \left( \frac{V_{OUT}}{V_S} \right) \quad (1)$$

## 7.10 Crosstalk

Crosstalk is defined as the ratio of the signal at the drain pin (D) of a different channel, when a signal is applied at the source pin (S<sub>x</sub>) of an on-channel. Figure 7-10 shows the setup used to measure, and the equation used to compute crosstalk.

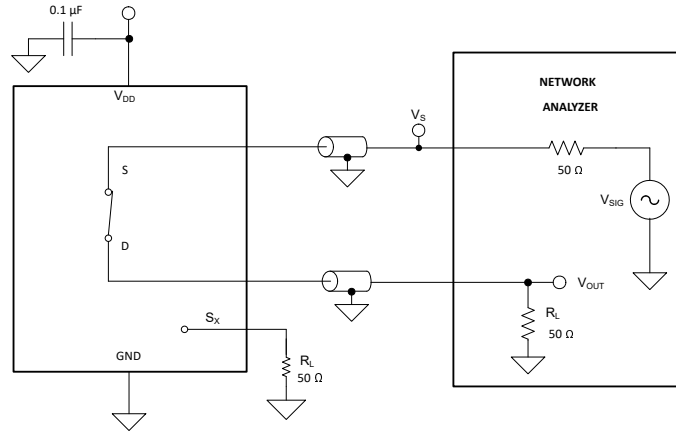


**Figure 7-10. Channel-to-Channel Crosstalk Measurement Setup**

$$\text{Channel - to - Channel Crosstalk} = 20 \times \text{Log} \left( \frac{V_{OUT}}{V_S} \right) \quad (2)$$

### 7.11 Bandwidth

Bandwidth is defined as the range of frequencies that are attenuated by less than 3 dB when the input is applied to the source pin (Sx) of an on-channel, and the output is measured at the drain pin (D) of the device. [Figure 7-11](#) shows the setup used to measure bandwidth.



**Figure 7-11. Bandwidth Measurement Setup**

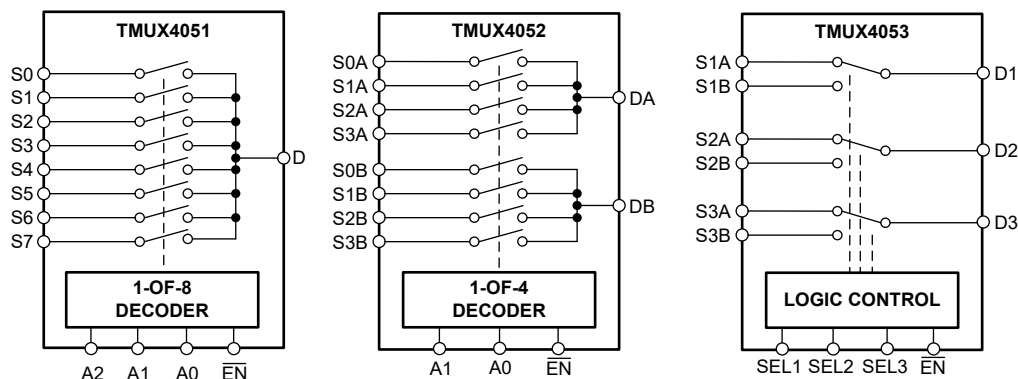
$$Attenuation = 20 \times \text{Log} \left( \frac{V_2}{V_1} \right) \tag{3}$$

## 8 Detailed Description

### 8.1 Overview

The TMUX4051 is an 8:1, single-ended (1-channel) mux, the TMUX4052 is a 4:1, differential (2-channel) multiplexer, and the TMUX4053 is 2:1, 3 channel switch. Each channel is turned on or turned off based on the state of the address lines and enable pin.

### 8.2 Functional Block Diagram



### 8.3 Feature Description

#### 8.3.1 Bidirectional Operation

The TMUX4051, TMUX4052, and TMUX4053 devices conduct equally well from source (Sx) to drain (Dx) or from drain (Dx) to source (Sx). Each signal path has very similar characteristics in both directions so they can be used as both multiplexers and demultiplexer to support analog signals.

#### 8.3.2 Rail-to-Rail Operation

The valid signal path input and output voltage for the TMUX4051, TMUX4052, and TMUX4053 ranges from  $V_{SS}$  to  $V_{DD}$ .

#### 8.3.3 1.8V Logic Compatible Inputs

The TMUX4051, TMUX4052, and TMUX4053 support 1.8V logic compatible control for all logic control inputs. 1.8V logic level inputs allows the multiplexers to interface with processors that have lower logic I/O rails and eliminates the need for an external voltage translator, which saves both space and BOM cost. For more information on 1.8V logic implementation, refer to [Simplifying Design with 1.8V Logic Muxes and Switches](#).

#### 8.3.4 Device Functional Modes

When the  $\overline{EN}$  pin of the TMUX405x devices is pulled low, one of the switches is closed based on the state of the address or select pins. When the  $\overline{EN}$  pin is pulled high, all the switches are in an open state regardless of the state of the address or select pins.

Unused logic control pins must be tied to GND or  $V_{DD}$  to be certain that the device does not consume additional current as highlighted in [Implications of Slow or Floating CMOS Inputs](#). Unused signal path inputs (Sx and Dx) should be connected to GND.

### 8.3.5 Truth Tables

Table 8-1, Table 8-2, and Table 8-3 provides the truth tables for the TMUX4051 respectively.

**Table 8-1. TMUX4051 Truth Table**

EN	A2	A1	A0	Selected Signal Path Connected To Drain (D) Pin
0	0	0	0	S0
0	0	0	1	S1
0	0	1	0	S2
0	0	1	1	S3
0	1	0	0	S4
0	1	0	1	S5
0	1	1	0	S6
0	1	1	1	S7
1	X <sup>(1)</sup>	X <sup>(1)</sup>	X <sup>(1)</sup>	All inputs are unselected (HI-Z)

(1) X denotes *do not care*.

**Table 8-2. TMUX4052 Truth Table**

EN	A1	A0	Selected Signal Path Connected To Drain (DA and DB) Pins
0	0	0	S0A to DA S0B to DB
0	0	1	S1A to DA S1B to DB
0	1	0	S2A to DA S2B to DB
0	1	1	S3A to DA S3B to DB
1	X <sup>(1)</sup>	X <sup>(1)</sup>	All inputs are unselected (HI-Z)

(1) X denotes *do not care*.

**Table 8-3. TMUX4053 Truth Table**

EN	SEL1	SEL2	SEL3	Selected Signal Path Connected To Drain Pins
0	0	X	X	S1A to D1
0	1	X	X	S1B to D1
0	X	0	X	S2A to D2
0	X	1	X	S2B to D2
0	X	X	0	S3A to D3
0	X	X	1	S3B to D3
1	X <sup>(1)</sup>	X <sup>(1)</sup>	X <sup>(1)</sup>	All inputs are unselected (HI-Z)

(1) X denotes *do not care*.

The Enable pin,  $\overline{\text{EN}}$ , of the TMUX405x devices have a weak internal pull-up resistor to put the devices into a disabled state upon power up. The SELx / Address pins (Ax) have weak internal pull-down resistors to put the switch into a defined logic state.

## 9 Application and Implementation

### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 9.1 Application Information

The TMUX405x devices offer good system performance across a wide operating supply (5V to 24V). These devices include 1.8V logic compatible control input pins that enable operation in systems with 1.8V I/O rails. These features make the TMUX405x a family of general purpose multiplexers and switches that can reduce system complexity, board size, and overall system cost.

### 9.2 Typical Application

One useful application to take advantage of the TMUX405x features is multiplexing various signals into an ADC that is integrated into an MCU. Utilizing an integrated ADC in an MCU allows a system to minimize cost with a potential tradeoff of system performance when compared to an external ADC. The multiplexer allows for multiple inputs or sensors to be monitored with a single ADC pin of the device, which is critical in systems with limited I/O. The TMUX4052 is suitable for a similar design example using differential signals, or as two 4:1 multiplexers.

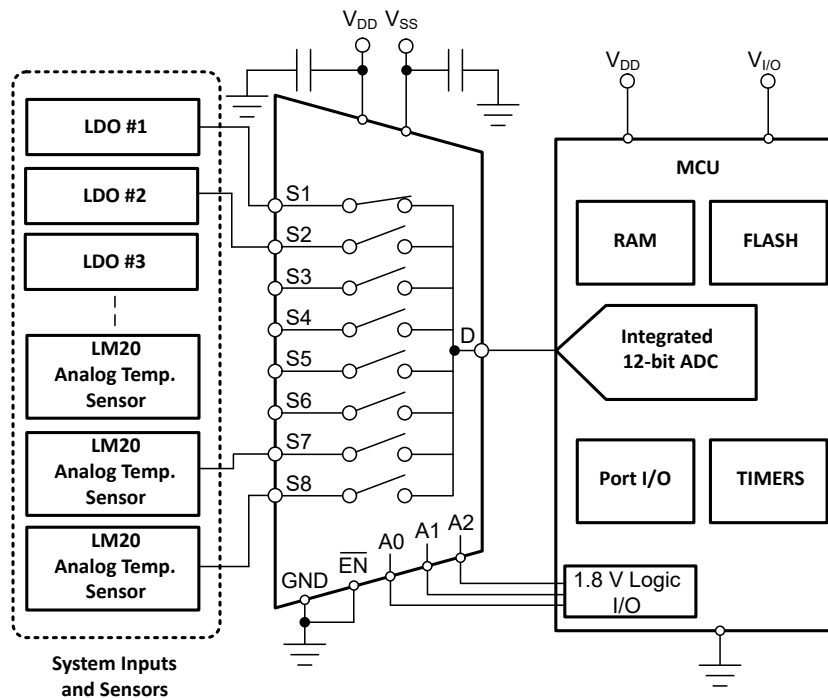


Figure 9-1. Multiplexing Signals to an Integrated ADC with TMUX4051



### 9.3 Design Requirements

Table 9-1 lists the parameters that must be used for this design example.

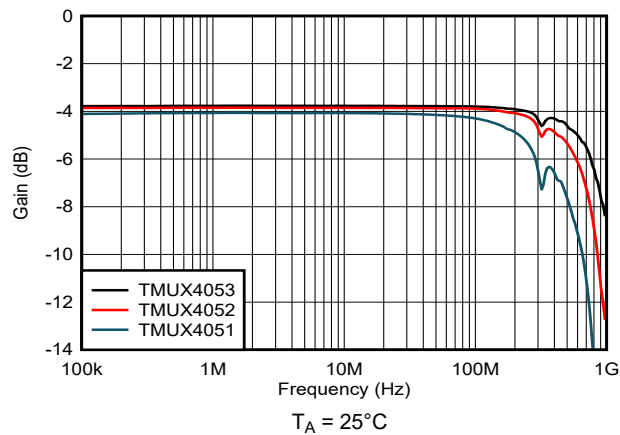
**Table 9-1. Design Parameters**

PARAMETERS	VALUES
Supply ( $V_{DD}$ )	12V
I/O signal range	0V to $V_{DD}$ (rail-to-rail)
Control logic thresholds	1.8V compatible

### 9.4 Detailed Design Procedure

The TMUX4051, TMUX4052, and TMUX4053 can operate without any external components except for the supply decoupling capacitors. The MCU can control the enable and address pins through GPIOs to toggle between various inputs of the multiplexer. The enable pin should be connected to ground if the functionality is not required in the system. All inputs being muxed to the ADC of the MCU must fall within the *Recommended Operating Conditions*, including signal range and continuous current. For this design with a supply of 12V, the signal range can be 0V to 12V.

### 9.5 Application Curves



**Figure 9-2. Bandwidth**

### 9.6 Power Supply Recommendations

The TMUX4051, TMUX4052, and TMUX4053 devices operate across a wide supply range of 5V to 24V.

Power-supply bypassing improves noise margin and prevents switching noise propagation from the supply pins to other components. Good power-supply decoupling is important to achieve optimum performance. For improved supply noise immunity, use a supply decoupling capacitor ranging from 0.1 $\mu\text{F}$  to 10 $\mu\text{F}$  from  $V_{DD}$  to ground and  $V_{SS}$  to ground. Place the bypass capacitors as close to the power supply pins of the device as possible using low-impedance connections. TI recommends using multi-layer ceramic chip capacitors (MLCCs) that offer low equivalent series resistance (ESR) and inductance (ESL) characteristics for power-supply decoupling purposes. For very sensitive systems or systems in harsh noise environments, avoiding the use of vias for connecting the capacitors to the device pins may offer superior noise immunity. The use of multiple vias in parallel lowers the overall inductance and is beneficial for connections to ground planes.



## 10 Device and Documentation Support

### 10.1 Documentation Support

#### 10.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [Simplifying Design with 1.8V logic Muxes and Switches application brief](#)
- Texas Instruments, [QFN/SON PCB Attachment application report](#)
- Texas Instruments, [Quad Flatpack No-Lead Logic Packages application report](#)

### 10.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](https://www.ti.com). Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 10.3 Support Resources

TI E2E™ [support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

### 10.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

### 10.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 10.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

## 11 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

<b>Changes from Revision D (July 2024) to Revision E (September 2024)</b>	<b>Page</b>
• Added TMUX4052 and TMUX4053 pin drawings.....	4

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<b>Changes from Revision C (July 2024) to Revision D (July 2024)</b>	<b>Page</b>
• Added back <a href="#">Figure 6-7</a> , <a href="#">Figure 6-8</a> , <a href="#">Figure 6-9</a> .....	14
• Added back <a href="#">Figure 9-2</a> .....	25

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<b>Changes from Revision B (March 2023) to Revision C (July 2024)</b>	<b>Page</b>
• Updated the numbering format for tables, figures, and cross-references throughout the document.....	1
• Updated Is(off) or Id(off) values.....	9
• Updated Ion values.....	9
• Added the Typical Characteristics.....	14

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<b>Changes from Revision A (September 2022) to Revision B (March 2023)</b>	<b>Page</b>
• Changed the status DYY and BQB packages from: <i>preview</i> to: <i>active</i> .....	1

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## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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